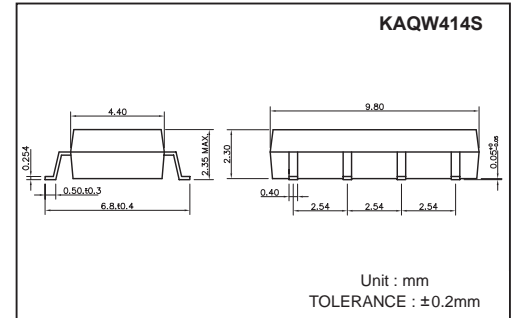


Features

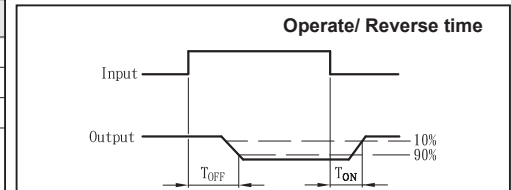
1. Normally Close, Single Pole Single Throw
2. Control 400VAC or DC Voltage
3. Switch 130mA Loads
4. LED control Current, 5mA
5. Low ON-Resistance
6. dv/dt, >500V/ms
7. Isolation Test Voltage, 1500VACrms



Absolute Maximum Ratings

(Ta=25°C)

Emitter (Input)	Detector (Output)
Reverse Voltage.....5.0V	Output Breakdown Voltage±400V
Continuous Forward Current50mA	Continuous Load Current±130mA
Peak Forward Current1A	Power Dissipation500mW
Power Dissipation100mW	
Derate Linearly from 25°C1.3mW/°C	
General Characteristics	
Isolation Test Voltage1500VACrms	Storage Temperature Range ...-40°C to +125°C
Isolation Resistance	Operating Temperature Range...-30°C to +85°C
Vio=500V, Ta=25°C≥10 ¹⁰ Ω	Junction Temperature.....100°C
Total Power Dissipation550mW	Soldering Temperature,
Derate Linearly from 25°C2.5mW/°C	2mm from case, 10 sec260°C



Electro-optical Characteristics

(Ta=25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Emitter (Input)						
Forward Voltage	V _F	I _F = 10mA		1.8	2.0	V
Operation Input Current	I _{FON}	V _L = ±20V, I _L = 100mA, t = 10ms			5	mA
Recovery Input Current	I _{FOFF}	V _L = ±20V, I _L ≤ 5uA	0.2			mA
Detector (Output)						
Output Breakdown Voltage	V _B	I _B = 50uA	400			V
Output Off-State Leakage	I _{TOFF}	V _T = 100V, I _F = 0mA		0.2	2	uA
I/O Capacitance	C _{ISO}	I _F = 0, f = 1MHz		6		pF
ON Resistance	R _{ON}	I _L = 100mA, I _F = 10mA		40	50	Ω
Reverse (ON) Time	T _{ON}	I _F = 10mA, V _L = ±20V		0.6	1.5	ms
Operate (OFF) Time	T _{OFF}	t = 10ms, I _L = ±100mA		0.3	1.0	ms

Mos Relay Schematic and Wiring Diagrams

Type	Schematic	Output configuration	Load	Connection	Wiring Diagrams
KAQW414S		2b	AC/DC	-	<p>(1) Two independent 1 Form B use</p> <p>(2) 2 Form B use</p>

Data Curve

